

Features

- Supply Voltage up to 40V
- Operating Voltage $V_S = 5V$ to 18V
- Typically 10 μA Supply Current During Sleep Mode
- Typically 40 μA Supply Current in Silent Mode
- Linear Low-drop Voltage Regulator:
 - Normal Mode: $V_{CC} = 5V \pm 2\%/50\text{ mA}$
 - Silent Mode: $V_{CC} = 5V \pm 7\%/50\text{ mA}$
 - Sleep Mode: V_{CC} is Switched Off
- V_{CC} Undervoltage Detection with Reset Output NRES (10 ms Reset Time)
- Voltage Regulator is Short-circuit and Over-temperature Protected
- LIN Physical Layer According to LIN Specification Revision 2.0
- Wake-up Capability via LIN Bus (90 μs Dominant)
- TXD Time-out Timer (9 ms)
- 60V Load-dump Protection at LIN Pin
- Bus Pin is Overtemperature and Short-circuit Protected versus GND and Battery
- High EMC Level
- 5V CMOS-Compatible I/O Pins to MCU
- ESD HBM 6kV at Pins LIN and VS
- Interference and Damage Protection According to ISO/CD7637
- Package: SO8

1. Description

ATA6620 is a fully integrated LIN transceiver, designed according to the LIN specification 2.0, with a low-drop voltage regulator (5V/50 mA). The combination of voltage regulator and bus transceiver makes it possible to develop simple, but powerful, slave nodes in LIN Bus systems. ATA6620 is designed to handle the low-speed data communication in vehicles (for example, in convenience electronics). Improved slope control at the LIN driver ensures secure data communication up to 20 kBaud with an RC oscillator for the protocol handling. The bus output is designed to withstand high voltage. Sleep mode (voltage regulator switched off) and Silent mode (communication off; V_{CC} voltage on) guarantee minimized current consumption.



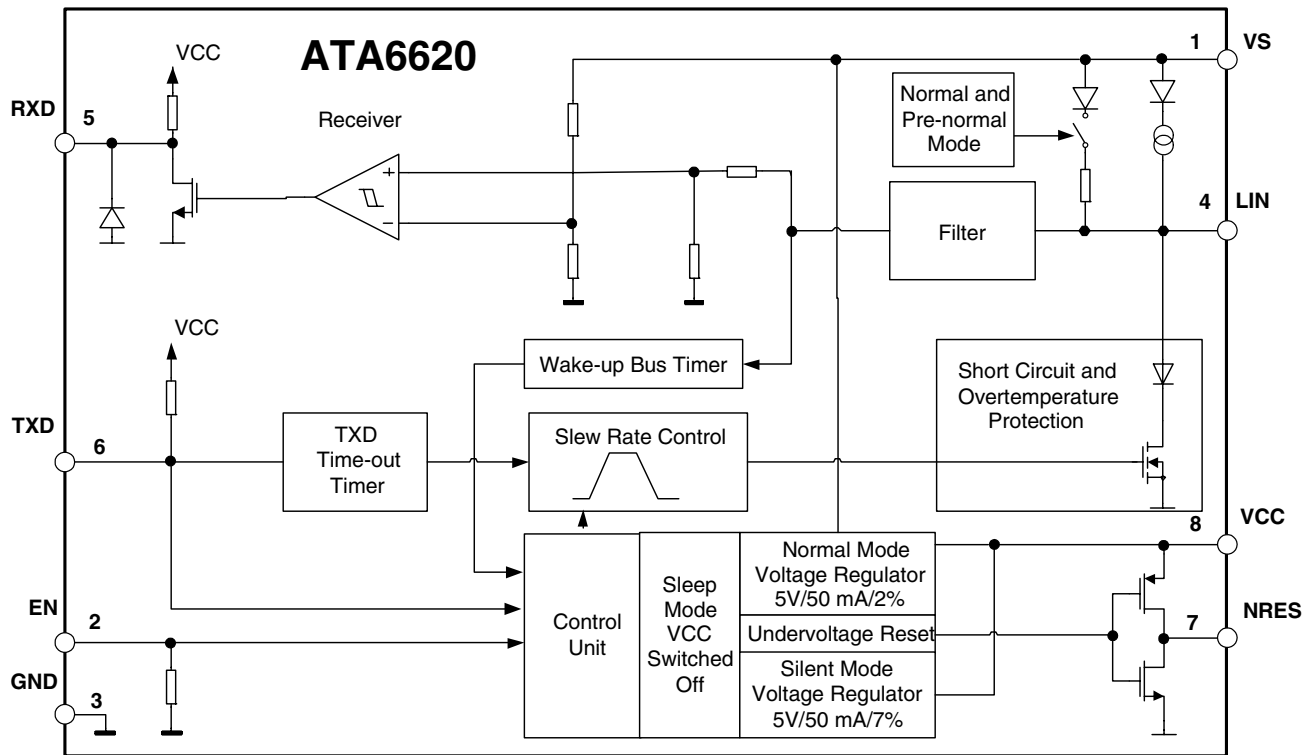
LIN Bus Transceiver with Integrated Voltage Regulator

ATA6620

Preliminary



Figure 1-1. Block Diagram



2. Pin Configuration

Figure 2-1. Pinning SO8

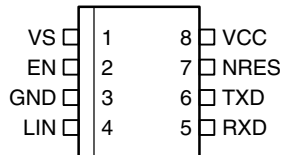


Table 2-1. Pin Description

| Pin | Symbol | Function |
|-----|--------|--|
| 1 | VS | Battery supply |
| 2 | EN | Enables Normal mode if the input is high |
| 3 | GND | Ground |
| 4 | LIN | LIN bus line input/output |
| 5 | RXD | Receive data output |
| 6 | TXD | Transmit data input |
| 7 | NRES | Output undervoltage reset, low at reset |
| 8 | VCC | Output voltage regulator 5V/50 mA |

3. Functional Description

3.1 Supply Pin (VS)

LIN operating voltage is $V_S = 5V$ to $18V$. An undervoltage detection is implemented to disable transmission if V_S falls below $5V$, in order to avoid false bus messages. After switching on V_S , the IC starts with the Pre-normal mode and the voltage regulator is switched on (that is, $5V/50$ mA output capability).

The supply current in Sleep mode is typically $10\text{ }\mu A$ and $40\text{ }\mu A$ in Silent mode.

3.2 Ground Pin (GND)

The IC is neutral on the LIN pin in case of GND disconnection. It is able to handle a ground shift up to $3V$ for supply voltage above $9V$ at the VS pin.

3.3 Voltage Regulator Output Pin (VCC)

The internal $5V$ voltage regulator is capable of driving loads with up to 50 mA, supplying the microcontroller and other ICs on the PCB. It is protected against overload by means of current limitation and overtemperature shut-down. Furthermore, the output voltage is monitored and will cause a reset signal at the NRES output pin if it drops below a defined threshold V_{thun} .

3.4 Undervoltage Reset Output (NRES)

This push-pull output is supplied from the V_{CC} voltage. If the V_{CC} voltage falls below the undervoltage detection threshold of V_{thun} , NRES switches to low after t_{res_f} (Figure 4-6 on page 9). Even if $V_{CC} = 0V$ the NRES stays low, because it is internally driven from the V_S voltage. If V_S voltage ramps down, NRES stays low until $V_S < 1.5V$ and then becomes highly resistant.

The implemented undervoltage delay keeps NRES low for $t_{Reset} = 10$ ms after V_{CC} reaches its nominal value.

3.5 Bus Pin (LIN)

A low-side driver with internal current limitation and thermal shutdown, as well as an internal pull-up resistor according to LIN specification 2.0 is implemented. The voltage range is from $-27V$ to $+60V$. This pin exhibits no reverse current from the LIN bus to V_S , even in the case of a GND shift or V_{Batt} disconnection. The LIN receiver thresholds are compatible with the LIN protocol specification.

The fall time (from recessive to dominant) and the rise time (from dominant to recessive) are slope controlled. The output has a short-circuit limitation. This is a self-adapting current limitation; that is, during current limitation, as the chip temperature increases, the current decreases.

3.6 Input Pin (TXD)

This pin is the microcontroller interface to control the state of the LIN output. TXD must be pulled to ground in order to drive the LIN bus low. If TXD is high or unconnected (internal pull-up resistor), the LIN output transistor is turned off and the bus is in the recessive state.

3.7 Dominant Time-out Function (TXD)

The TXD input has an internal pull-up resistor. An internal timer prevents the bus line from being driven permanently in the dominant state. If TXD is forced to low longer than $T_{DOM} > 4 \text{ ms}$, the LIN bus driver is switched to the recessive state. To reset this dominant time-out mode, TXD must be switched to high ($>10 \mu\text{s}$) before normal data transmission can be started.

3.8 Output Pin (RXD)

This pin reports the state of the LIN bus to the microcontroller. LIN high (recessive state) is reported by a high level at RXD; LIN low (dominant state) is reported by a low level at RXD. The output has an internal pull-up structure with typically $5 \text{ k}\Omega$ to V_{CC} . The AC characteristics are measured with an external load capacitor of 20 pF .

The output is short-circuit protected. In unpowered mode (that is, $V_S = 0\text{V}$), RXD is switched off.

3.9 Enable Input Pin (EN)

This pin controls the operation mode of the interface. After power up of V_S (battery), the IC switches to Pre-normal mode, even if EN is low or unconnected (internal pull-down resistor). If EN is high, the interface is in Normal mode.

A falling edge at EN while TXD is still high forces the device to Silent mode. A falling edge at EN while TXD is low forces the device to Sleep mode.

4. Mode of Operation

Figure 4-1. Mode of Operation

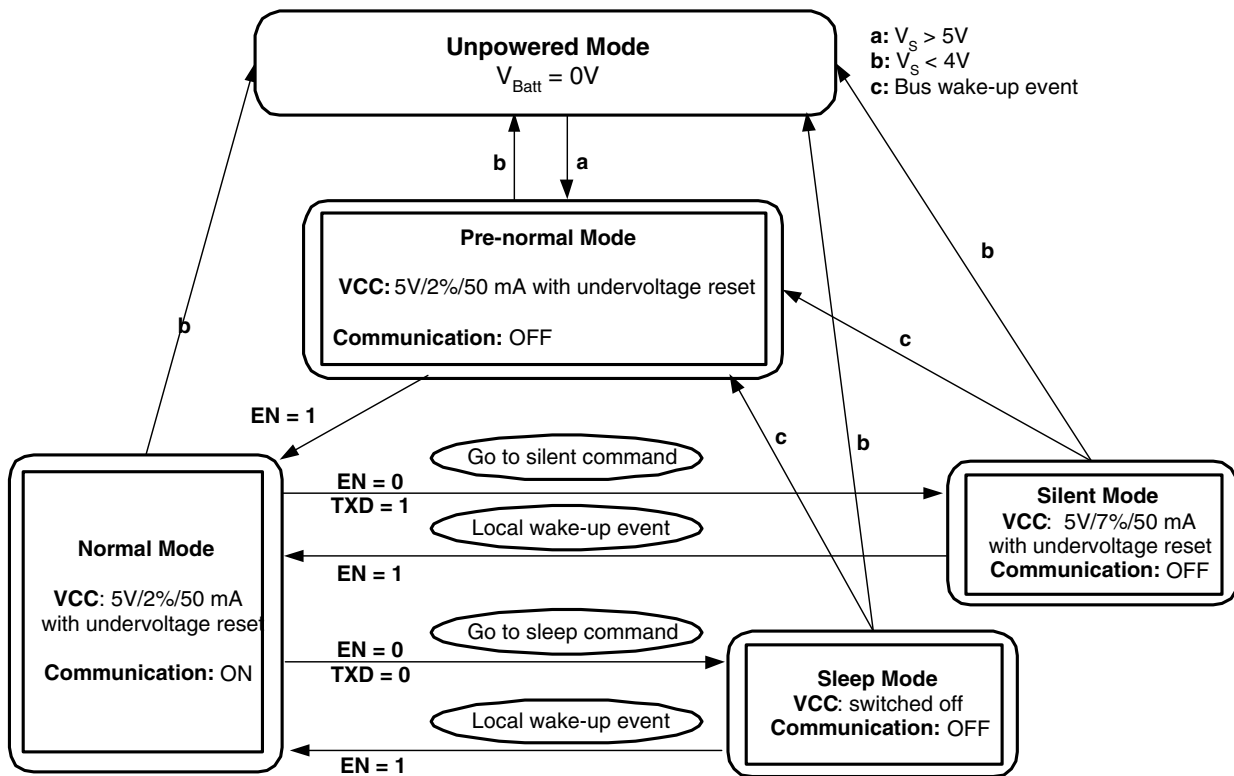


Table 4-1. Mode of Operation

| Mode of Operation | Communication | V _{CC} | RXD | LIN |
|-------------------|---------------|-----------------|-----|-----------|
| Pre-normal | OFF | 5V | 5V | Recessive |
| Normal | ON | 5V | 5V | Recessive |
| Silent | OFF | 5V | 5V | Recessive |
| Sleep | OFF | 0V | 0V | Recessive |

4.1 Normal Mode

This is the normal transmitting and receiving mode of the LIN Interface, in accordance with LIN specification 2.0. The V_{CC} voltage regulator operates with a 5V output voltage, with a low tolerance of $\pm 2\%$ and a maximum output current of 50 mA.

If an undervoltage condition occurs, NRES is switched to low and the ATA6620 changes state to Pre-normal mode. All features are available.

4.2 Silent Mode

A falling edge at EN while TXD is high switches the IC into Silent mode. The TXD Signal has to be logic high during the Mode Select window ([Figure 4-2 on page 6](#)). For EN and TXD either two independent outputs can be used, or two outputs from the same microcontroller port; in the second case, the mode change is only one command.

In Silent mode the transmission path is disabled. Supply current from V_{Batt} is typically I_{VSSi} = 40 μ A with no load at the V_{CC} regulator.

The overall supply current from V_{Batt} is the result of 40 μ A plus the V_{CC} regulator output current I_{VCCs}.

The 5V regulator is in low tolerance mode (4.65V to 5.35V) and can source up to 50 mA. In Silent mode the internal slave termination between pin LIN and pin VS is disabled to minimize the power dissipation in case pin LIN is short-circuited to GND. Only a weak pull-up current (typically 10 μ A) between pin LIN and pin VS is present.

The Silent mode voltage is sufficient to run an external microcontroller on the ECU, for example in Power Down mode. The undervoltage reset is V_{CCthS} < 4.4V. If an undervoltage condition occurs, NRES is switched to low and the ATA6620 changes state to Pre-normal mode.

A falling edge at pin LIN followed by a dominant bus level maintained for a certain time period (T_{bus}) results in a remote wake-up request. The device switches from Silent mode to Pre-normal mode, then the internal LIN slave termination resistor is switched on. The remote wake-up request is indicated by a low level at pin RXD to interrupt the microcontroller. ([Figure 4-5 on page 8](#))

With EN high, ATA6620 switches directly from Silent to Normal mode.

Figure 4-2. Switch to Silent Mode

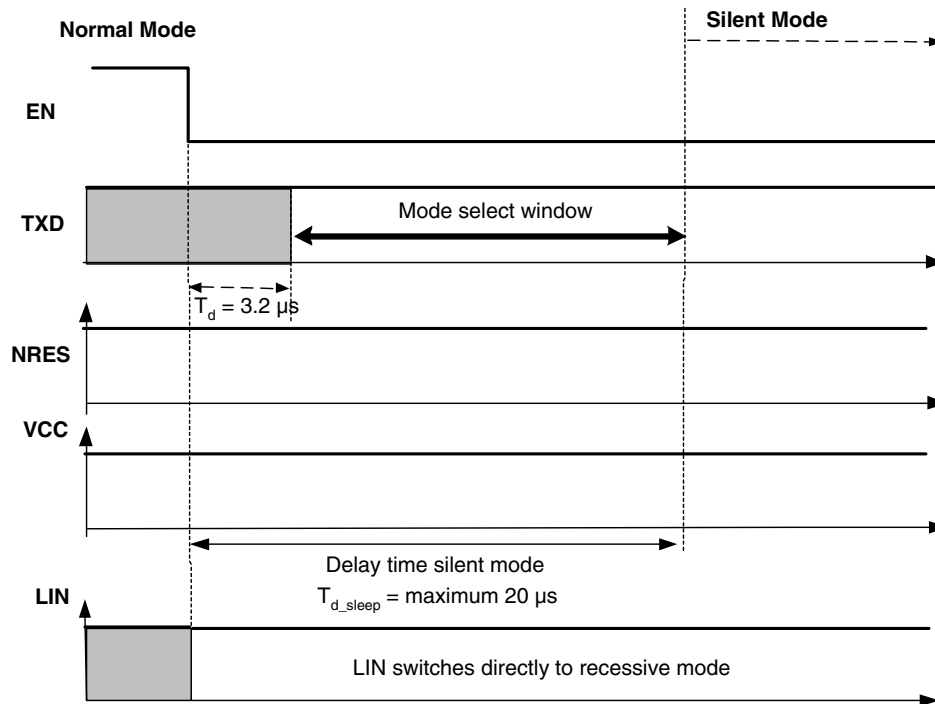
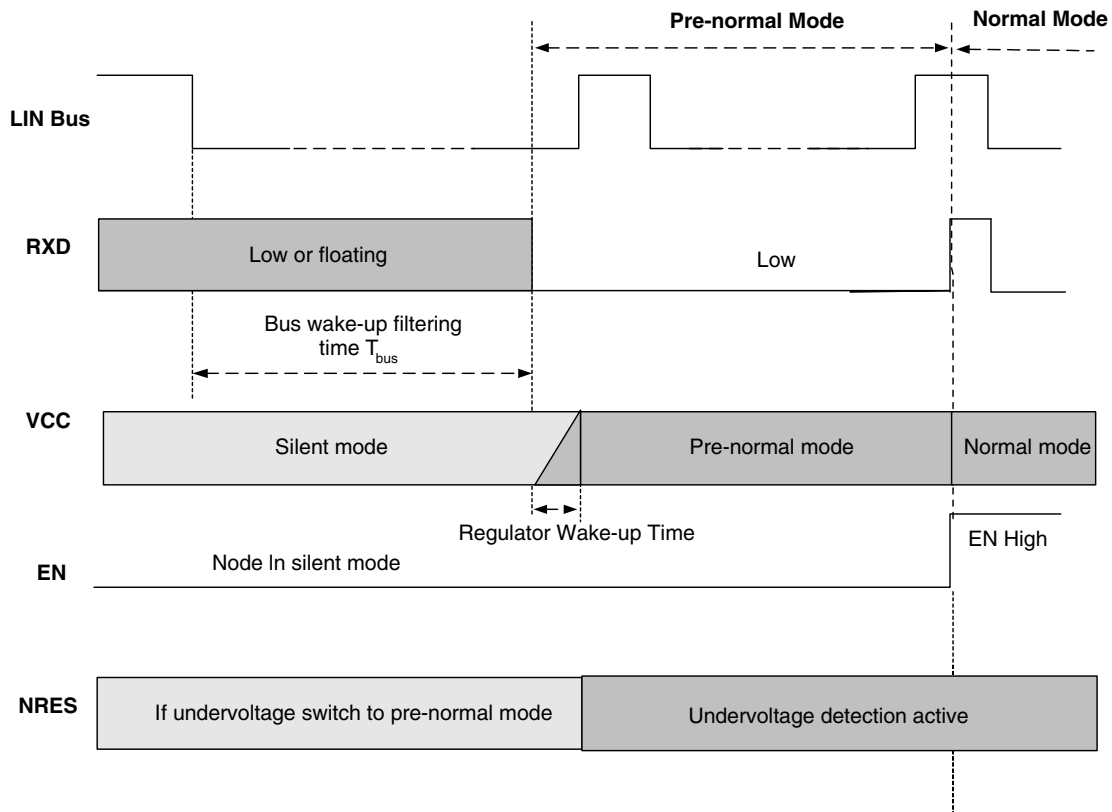


Figure 4-3. LIN Wake-up Waveform Diagram from Silent Mode



4.3 Sleep Mode

A falling edge at EN while TXD is low switches the IC into Sleep mode. The TXD Signal has to be logic low during the Mode Select window ([Figure 4-4 on page 8](#)). We recommend using the same microcontroller port for EN as for TXD; in this case the mode change is only one command.

In Sleep mode the transmission path is disabled. Supply current from V_{Batt} is typically $I_{V_{SS}sleep} = 10 \mu A$. The V_{CC} regulator is switched off; NRES and RXD are low. The internal slave termination between pin LIN and pin VS is disabled to minimize the power dissipation in case pin LIN is short-circuited to GND. Only a weak pull-up current (typically $10 \mu A$) between pin LIN and pin VS is present.

A falling edge at pin LIN followed by a dominant bus level maintained for a certain time period (T_{bus}) results in a remote wake-up request. The device switches from Sleep mode to Pre-normal mode. The V_{CC} regulator is activated and the internal LIN slave termination resistor is switched on. The remote wake-up request is indicated by a low level at pin RXD to interrupt the microcontroller. ([Figure 4-5 on page 8](#))

With EN high you can switch directly from Silent to Normal mode. In the application where the ATA6620 supplies the microcontroller, the wake-up from Sleep mode is only possible via pin LIN.

4.4 Pre-normal Mode

At system power-up the device automatically switches to Pre-normal mode. The voltage regulator is switched on ($V_{CC} = 5V/50 mA$) (see [Figure 4-4 on page 8](#)) after typically $t_{V_{CC}} = 1 ms$. The NRES output switches to low for $t_{res} = 10 ms$ and sends a reset to the microcontroller. LIN communication is switched off, and the undervoltage detection is active.

A power-down of V_{Batt} ($V_S < 4V$) during Silent or Sleep mode switches into Pre-normal mode after powering up the IC.

4.5 Unpowered Mode

If battery voltage is connected to the application circuit ([Figure 4-6 on page 9](#)), the voltage at the VS pin increases due to the block capacitor. When V_S is higher than the V_S undervoltage threshold, V_{Sth} , the IC-mode changes from Unpowered to Pre-normal mode. The V_{CC} output voltage reaches nominal value after $t_{V_{CC}}$. This time depends on the V_{CC} capacitor and the load.

NRES is low for the reset time delay t_{Reset} ; no mode change is possible during this time.

Figure 4-4. Switch to Sleep Mode

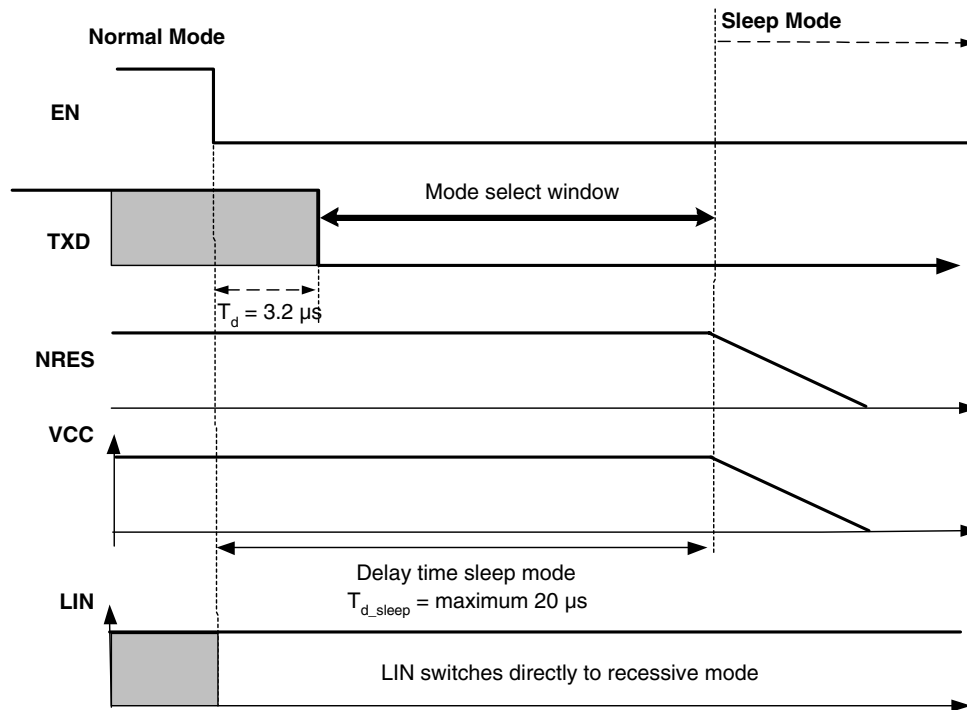


Figure 4-5. LIN Wake-up Diagram from Sleep Mode

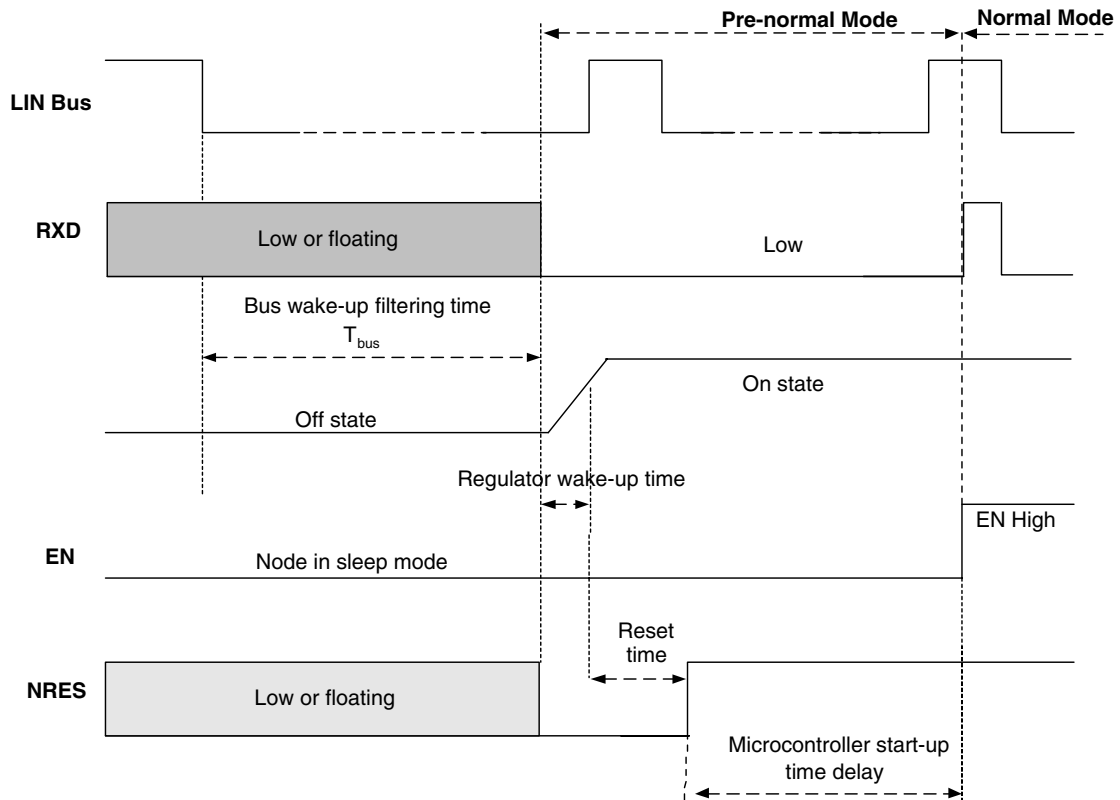
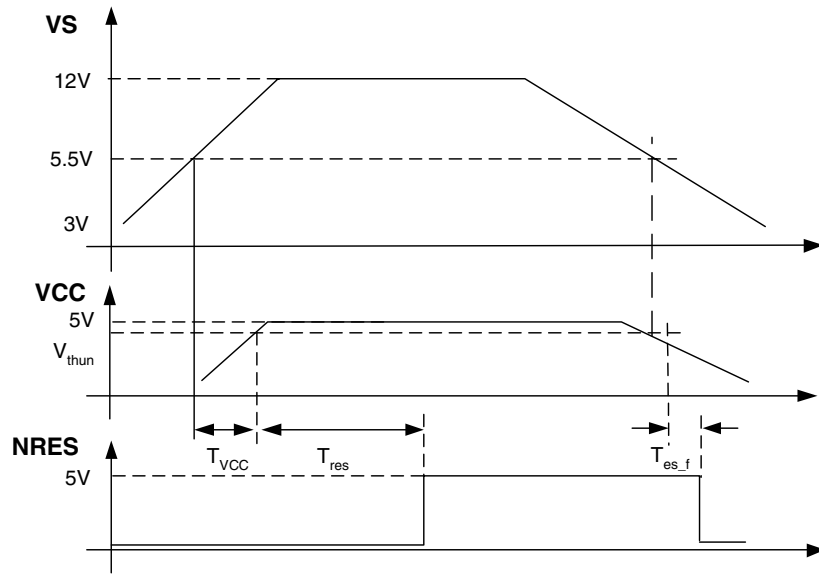


Figure 4-6. V_{CC} Voltage Regulator: Ramp Up and Undervoltage



5. Fail Safe Features

- During a short circuit at LIN, the output limits the output current to I_{BUS_LIM} . Due to the power dissipation, the chip temperature exceeds T_{LINoff} and the LIN output is switched off. The chip cools down and after a hysteresis of T_{hys} , switches the output on again. During LIN overtemperature switch-off, the V_{CC} regulator works independently.
- There are now reverse currents $< 3 \mu A$ at pin LIN during loss of V_{Batt} or GND. This is optimal behavior for bus systems where some slave nodes are supplied from battery or ignition.
- During a short circuit at VCC, the output limits the output current to I_{VCCn} . Because of undervoltage, NRES switches to low and sends a reset to the microcontroller. The IC switches into Pre-normal mode. If the chip temperature exceeds the value T_{VCCoff} , the V_{CC} output switches off. The chip cools down and after a hysteresis of T_{hys} , switches the output on again. Because of Pre-normal mode, the V_{CC} voltage will switch on again although EN is switched off from the microcontroller. The microcontroller can then start with normal operation.
- Pin EN provides a pull-down resistor to force the transceiver into recessive mode if EN is disconnected.
- Pin RXD is set floating if V_{Batt} is disconnected.
- Pin TXD provides a pull-up resistor to force the transceiver into recessive mode if TXD is disconnected.

6. Voltage Regulator

The voltage regulator needs an external capacitor for compensation and to smooth the disturbances from the microcontroller. It is recommended to use an electrolytic capacitor with $C > 1.8 \mu\text{F}$ and a tantalum capacitor with $C = 100 \text{ nF}$. The values of these capacitors can be varied by the customer, depending on the application.

During mode change from Silent to Normal mode, the voltage regulator ramps up to 6V for only a few microseconds before it drops back to 5V. This behavior depends on the value of the load capacitor. With $4.7 \mu\text{F}$, the overshoot voltage has its greatest value. This voltage decreases with higher or lower load capacitors.

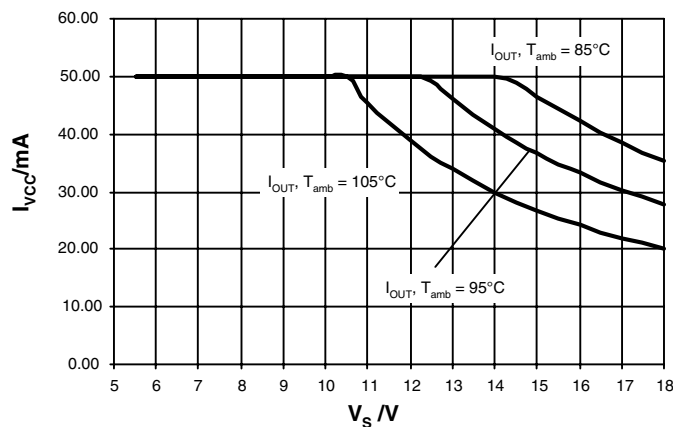
With this special SO8 package (fused lead frame to pin3) an R_{thja} of 100 K/W is achieved.

Therefore it is recommended to connect pin 3 with a wide GND plate on the printed board to get a good heat sink.

The main power dissipation of the IC is created from the V_{CC} output current I_{VCC} , which is needed for the application.

Figure 6-1 shows the safe operating area of the ATA6620.

Figure 6-1. Safe Operating Area versus V_{CC} Output Current and Supply Voltage V_{S} at Different Ambient Temperatures



7. Absolute Maximum Ratings

Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

| Parameters | Symbol | Min. | Typ. | Max. | Unit |
|---|--------------|-------------|------|-------------|--------|
| V_S - Continuous supply voltage | | −0.3 | | +40 | V |
| Logic pins (RxD, TxD, EN, NRES) | | −0.3 | | +6.5 | V |
| LIN - DC voltage - Transient voltage | | −40 −150 | | +60 +100 | V V |
| V_{CC} - DC voltage | | −0.3 | | +6.5 | V |
| ESD (DIN EN 6100–4–2) Pin LIN, V_S versus GND according to LIN specification EMC Evaluation V 1.3 | | −6 | | +6 | kV |
| HBM ESD S5.1 – all pins | | −2 | | +2 | kV |
| CDM ESD STM 5.3.1–1999 - All pins | | −500 | | +500 | V |
| Junction temperature | T_j | −40 | | +150 | °C |
| Storage temperature | T_s | −55 | | +150 | °C |
| Operating ambient temperature | T_a | −40 | | +125 | °C |
| Thermal resistance junction to ambient (free air) | R_{thja} | | | 145 | K/W |
| Special heat sink at GND (pin 3) on PCB | R_{thja} | | | 100 | K/W |
| Thermal shutdown of V_{CC} regulator | T_{VCCoff} | 155 | 165 | 175 | °C |
| Thermal shutdown of LIN output | T_{LINoff} | 155 | 165 | 175 | °C |
| Thermal shutdown hysteresis | T_{hys} | | 7 | | °C |

8. Electrical Characteristics

5V < V_S < 18V, T_{amb} = -40°C to 125°C

| No. | Parameters | Test Conditions | Pin | Symbol | Min. | Typ. | Max. | Unit | Type* |
|----------|---------------------------------------|---|-----|----------------------|------|------|------------------------|------|-------|
| 1 | VS Pin | | | | | | | | |
| 1.1 | Nominal DC voltage range | | VS | V _S | 5 | 13.5 | 18 | V | A |
| 1.2 | Supply current in Sleep mode | Sleep mode V _{lin} > V _{Batt} - 0.5V V _{Batt} < 14V (25°C to 125°C) | VS | I _{VSsleep} | | 10 | 20 | μA | A |
| 1.3 | Supply current in Silent mode | Bus recessive; V _{Batt} < 14V (25°C to 125°C) Without load at V _{CC} | VS | I _{VSSi} | | 40 | 50 | μA | A |
| 1.4 | Supply current in Normal mode | Bus recessive Without load at V _{CC} | VS | I _{VSrec} | | | 4 | mA | A |
| 1.5 | Supply current in Normal mode | Bus dominant V _{CC} load current 50 mA | VS | I _{VSdom} | | | 55 | mA | A |
| 1.6 | Power On Reset threshold | | VS | POR _{th} | 3 | | 3.3 | V | D |
| 1.7 | Power On Reset threshold hysteresis | | VS | POR _{hys} | | 0.1 | | V | D |
| 1.8 | V _S undervoltage threshold | | VS | V _{Sth} | 4.0 | 4.5 | 5 | V | A |
| 1.9 | VS undervoltage threshold hysteresis | | VS | V _{Sth_hys} | | 0.2 | | V | A |
| 2 | RXD Output Pin | | | | | | | | |
| 2.1 | Low level input current | Normal mode; V _{LIN} = 0V V _{RXD} = 0.4V | RXD | I _{RXD} | 2 | 5 | 8 | mA | A |
| 2.2 | Low level output voltage | I _{RXD} = 1 mA | RXD | V _{RXDL} | | | 0.4 | V | A |
| 2.3 | High level output voltage | I _{RXD} = -1 mA | RXD | V _{RXDH} | 4.2 | | | V | A |
| 2.4 | Internal resistor to V _{CC} | | RXD | R _{RXD} | 3 | 5 | 7 | kΩ | A |
| 3 | TXD Input Pin | | | | | | | | |
| 3.1 | Low level voltage input | | TXD | V _{TXDL} | -0.3 | | +1.5 | V | A |
| 3.2 | High level voltage input | | TXD | V _{TXDH} | 3.5 | | V _{CC} + 0.3V | V | A |
| 3.3 | Pull-up resistor | V _{TXD} = 0V | TXD | R _{TXD} | 125 | 250 | 600 | kΩ | A |
| 3.4 | High level leakage current | V _{TXD} = 5V | TXD | I _{TXD} | -3 | | +3 | μA | A |
| 4 | EN Input Pin | | | | | | | | |
| 4.1 | Low level voltage input | | EN | V _{ENL} | -0.3 | | +1.5 | V | A |
| 4.2 | High level voltage input | | EN | V _{ENH} | 3.5 | | V _{CC} + 0.3V | V | A |
| 4.3 | Pull-down resistor | V _{EN} = 5V | EN | R _{EN} | 125 | 250 | 600 | kΩ | A |
| 4.4 | Low level input current | V _{EN} = 0V | EN | I _{EN} | -3 | | +3 | μA | A |

*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

8. Electrical Characteristics (Continued)

5V < V_S < 18V, T_{amb} = -40°C to 125°C

| No. | Parameters | Test Conditions | Pin | Symbol | Min. | Typ. | Max. | Unit | Type* |
|----------|--|--|------|----------------------|-------------------------------------|------|------|------|-------|
| 5 | NRES Output Pin | | | | | | | | |
| 5.1 | High level output voltage | V _S ≥ 5.5V; I _{NRES} = -1 mA | NRES | V _{NRESH} | 4.2 | | | V | A |
| 5.2 | Low level output voltage | V _S ≥ 5.5V; I _{NRES} = -1 mA | NRES | V _{NRESL} | | | 0.4 | V | A |
| 5.3 | Low level output low | 10 kΩ to V _{CC} ; V _{CC} = 0.8V | NRES | V _{NRESLL} | | | 0.2 | V | A |
| 5.4 | Undervoltage reset time | V _{VS} ≥ 5.5V C _{NRES} = 20 pF | NRES | t _{Reset} | 7 | | 13 | ms | A |
| 5.5 | Reset debounce time for falling edge | V _{VS} ≥ 5.5V C _{NRES} = 20 pF | NRES | t _{res_f} | | | 5 | μs | A |
| 6 | Voltage Regulator VCC Pin in Normal and Pre-normal Mode | | | | | | | | |
| 6.1 | Output voltage V _{CC} | 5.5V < V _S < 18V (0 mA – 50 mA) | VCC | V _{CCnor} | 4.9 | | 5.1 | V | A |
| 6.2 | Output voltage V _{CC} at low V _S | 3.3V < V _S < 5.5V (0 mA – 50 mA) | VCC | V _{CClow} | V _{VS} – V _D | | 5.1 | V | A |
| 6.3 | Regulator drop voltage | V _S > 4.0V, I _{VCC} = 20 mA | VCC | V _D | | | 250 | mV | A |
| 6.4 | Regulator drop voltage | V _S > 4.0V, I _{VCC} = 50 mA | VCC | V _D | | | 500 | mV | A |
| 6.5 | Regulator drop voltage | V _S > 3.3V, I _{VCC} = 15 mA | VCC | V _D | | | 200 | mV | A |
| 6.6 | Output current | V _S > 3V | VCC | I _{VCC} | -50 | | | mA | A |
| 6.7 | Output current limitation | V _S > 0V | VCC | I _{VCCs} | -200 | -130 | | mA | A |
| 6.8 | Load capacity | ESR < 5Ω | VCC | C _{load} | 1.8 | 2.2 | | μF | A |
| 6.9 | V _{CC} undervoltage threshold | Referred to V _{CC} V _S > 5.5V | VCC | V _{thunN} | 4.4 | | 4.8 | V | A |
| 6.10 | Hysteresis of undervoltage threshold | Referred to V _{CC} V _S > 5.5V | VCC | V _{hysthun} | 40 | | | mV | A |
| 6.11 | Ramp up time V _S > 5.5V to V _{CC} > 4.9V | C _{VCC} = 2.2 μF R _{load} at V _{CC} : 100Ω | VCC | t _{VCC} | | 1 | 2 | ms | A |
| 7 | Voltage Regulator VCC Pin in Silent Mode | | | | | | | | |
| 7.1 | Output voltage V _{CC} | 5.5V < V _S < 18V (0 mA – 50 mA) | VCC | V _{CCnor} | 4.65 | | 5.35 | V | A |
| 7.2 | Output voltage V _{CC} at low V _S | 3.3V < V _S < 5.5V (0 mA – 50 mA) | VCC | V _{CClow} | V _{VS} – V _D | | 5.1 | V | A |
| 7.3 | Regulator drop voltage | V _S > 3.3V, I _{VCC} = 15 mA | VCC | V _D | | | 200 | mV | A |
| 7.4 | At V _{CC} undervoltage threshold the state switches back to Pre-normal mode | Referred to V _{CC} V _S > 5.5 | VCC | V _{thunS} | 3.9 | | 4.4 | V | A |
| 7.5 | Hysteresis of undervoltage threshold | Referred to V _{CC} V _S > 5.5V | VCC | V _{hysthun} | 40 | | | mV | D |
| 7.6 | Output current limitation | V _S > 0V | VCC | I _{VCCs} | -200 | -130 | | mA | A |

*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

8. Electrical Characteristics (Continued)

5V < V_S < 18V, T_{amb} = -40°C to 125°C

| No. | Parameters | Test Conditions | Pin | Symbol | Min. | Typ. | Max. | Unit | Type* |
|------|--|---|-----|--------------------------|----------------------|------|-------------------|----------------|-------|
| 8 | LIN Bus Driver: Bus Load Conditions: Load 1 (Small): 1 nF, 1 kΩ; Load 2 (Large): 10 nF, 500Ω; R_{RXD} = 5 kΩ; C_{RXD} = 20 pF 10.5, 10.6 and 10.7 Specifies the Timing Parameters for Proper Operation at 20 Kbps | | | | | | | | |
| 8.1 | Driver recessive output voltage | V _{TXD} = 0V; I _{LIN} = 0 mA | LIN | V _{BUSrec} | 0.9 × V _S | | V _S | V | A |
| 8.2 | Driver dominant voltage | V _{VS} = 7.3V R _{load} = 500 Ω | LIN | V _{LoSUP} | | | 1.2 | V | A |
| 8.3 | Driver dominant voltage | V _{VS} = 18V R _{load} = 500 Ω | LIN | V _{HiSUP} | | | 2 | V | A |
| 8.4 | Driver dominant voltage | V _{VS} = 7.3V R _{load} = 1000 Ω | LIN | V _{LoSUP_1k} | 0.6 | | | V | A |
| 8.5 | Driver dominant voltage | V _{VS} = 18V R _{load} = 1000 Ω | LIN | V _{HiSUP_1k} | 0.8 | | | V | A |
| 8.6 | Pull-up resistor to V _S | The serial diode is mandatory | LIN | R _{LIN} | 20 | 30 | 60 | kΩ | A |
| 8.7 | Self-adapting current limitation V _{BUS} = V _{Batt_max} | T _j = 125°C T _j = 27°C T _j = -40°C | LIN | I _{BUS_LIM} | 52 100 150 | | 110 170 230 | mA mA mA | A |
| 8.8 | Input leakage current at the receiver including pull-up resistor as specified | Input Leakage current Driver off V _{BUS} = 0V V _{Batt} = 12V | LIN | I _{BUS_PAS_dom} | -1 | | | mA | A |
| 8.9 | Leakage current LIN recessive | Driver off 8V < V _{Batt} < 18V 8V < V _{BUS} < 18V V _{BUS} ≥ V _{Batt} | LIN | I _{BUS_PAS_rec} | | 15 | 20 | μA | A |
| 8.10 | Leakage current when control unit disconnected from ground. Loss of local ground must not affect communication in the residual network | GND _{Device} = V _S V _{Batt} = 12V 0V < V _{BUS} < 18V | LIN | I _{BUS_NO_gnd} | -10 | +0.5 | +10 | μA | A |
| 8.11 | Node has to sustain the current that can flow under this condition. Bus must remain operational under this condition | V _{Batt} disconnected V _{SUP_Device} = GND 0V < V _{BUS} < 18V | LIN | I _{BUS} | | 0.5 | 3 | μA | A |

*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

8. Electrical Characteristics (Continued)

5V < V_S < 18V, T_{amb} = -40°C to 125°C

| No. | Parameters | Test Conditions | Pin | Symbol | Min. | Typ. | Max. | Unit | Type* |
|-----------|---|---|-----|--|---------------------|------------------|-----------------------|------|-------|
| 9 | LIN Bus Receiver | | | | | | | | |
| 9.1 | Center of receiver threshold | $V_{BUS_CNT} = (V_{th_dom} + V_{th_rec})/2$ | LIN | V _{BUS_CNT} | $0.475 \times V_S$ | $0.5 \times V_S$ | $0.525 \times V_S$ | V | A |
| 9.2 | Receiver dominant state | V _{EN} = 5V | LIN | V _{BUSdom} | -27 | | $0.4 \times V_S$ | V | A |
| 9.3 | Receiver recessive state | V _{EN} = 5V | LIN | V _{BUSrec} | $0.6 \times V_S$ | | 40 | V | A |
| 9.4 | Receiver input hysteresis | V _{hys} = V _{th_rec} - V _{th_dom} | LIN | V _{BUShys} | $0.028 \times V_S$ | $0.1 \times V_S$ | $0.175 \times V_S$ | V | A |
| 9.5 | Wake detection LIN High level input voltage | | LIN | V _{LINH} | V _S - 1V | | V _S + 0.3V | V | A |
| 9.6 | Wake detection LIN Low level input voltage | I _{LIN} = typically -3 mA | LIN | V _{LINL} | -27 | | V _S - 3V | V | A |
| 9.7 | LIN pull-up current | V _S < 27V | LIN | I _{LIN} | -30 | -10 | | μA | A |
| 10 | Internal Timers | | | | | | | | |
| 10.1 | Dominant time for wake-up via LIN bus | V _{LIN} = 0V | | t _{bus} | 30 | 90 | 150 | μs | A |
| 10.2 | Time delay for mode change from Pre-normal into Normal mode via pin EN | V _{EN} = 5V | | t _{norm} | 1 | 5 | 10 | μs | A |
| 10.3 | Time delay for mode change from Normal mode to Sleep mode via pin EN | V _{EN} = 0V | | t _{sleep} | 2 | 7 | 12 | μs | A |
| 10.4 | TXD dominant time out timer | V _{TXD} = 0V | | t _{dom} | 5 | 10 | 20 | ms | A |
| 10.5 | Duty cycle 1 | TH _{Rec(max)} = $0.744 \times V_S$; TH _{Dom(max)} = $0.581 \times V_S$; V _S = 7.0V to 18V; t _{Bit} = 50 ms D1 = t _{bus_rec(min)} / (2 × t _{Bit}) | | D1 | 0.396 | | | | A |
| 10.6 | Duty cycle 2 | TH _{Rec(min)} = $0.422 \times V_S$; TH _{Dom(min)} = $0.284 \times V_S$; V _S = 7.0V to 18V; t _{Bit} = 50ms D2 = t _{bus_rec(max)} / (2 × t _{Bit}) | | D2 | | | 0.581 | | A |
| 10.7 | Slope time falling and rising edge at LIN | | | t _{SLOPE_fall} t _{SLOPE_rise} | 3.5 | | 22.5 | μs | A |
| 11 | Receiver Electrical AC Parameters of the LIN Physical Layer LIN Receiver, RXD Load Conditions (C_{RXD}): 20 pF; R_{pull-up} = 2.4 kΩ | | | | | | | | |
| 11.1 | Propagation delay of receiver Figure 4-4 | t _{rec_pd} = max(t _{rx_pdr} , t _{rx_pdf}) | | t _{rx_pd} | | | 6 | μs | A |
| 11.2 | Symmetry of receiver propagation delay rising edge minus falling edge | t _{rx_sym} = t _{rx_pdr} - t _{rx_pdf} | | t _{rx_sym} | -2 | | +2 | μs | A |

*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Figure 8-1. Definition of Bus Timing Characteristics

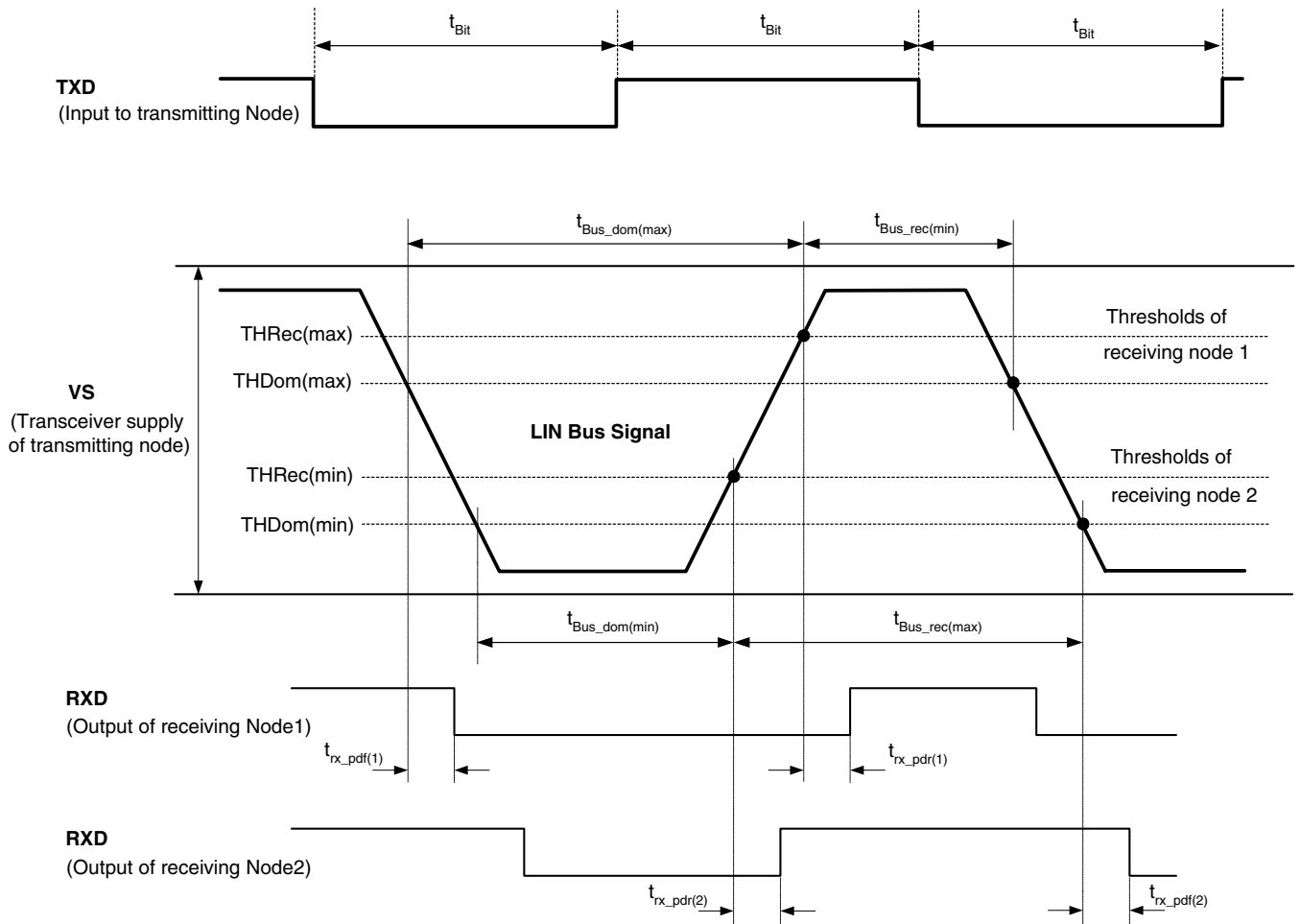
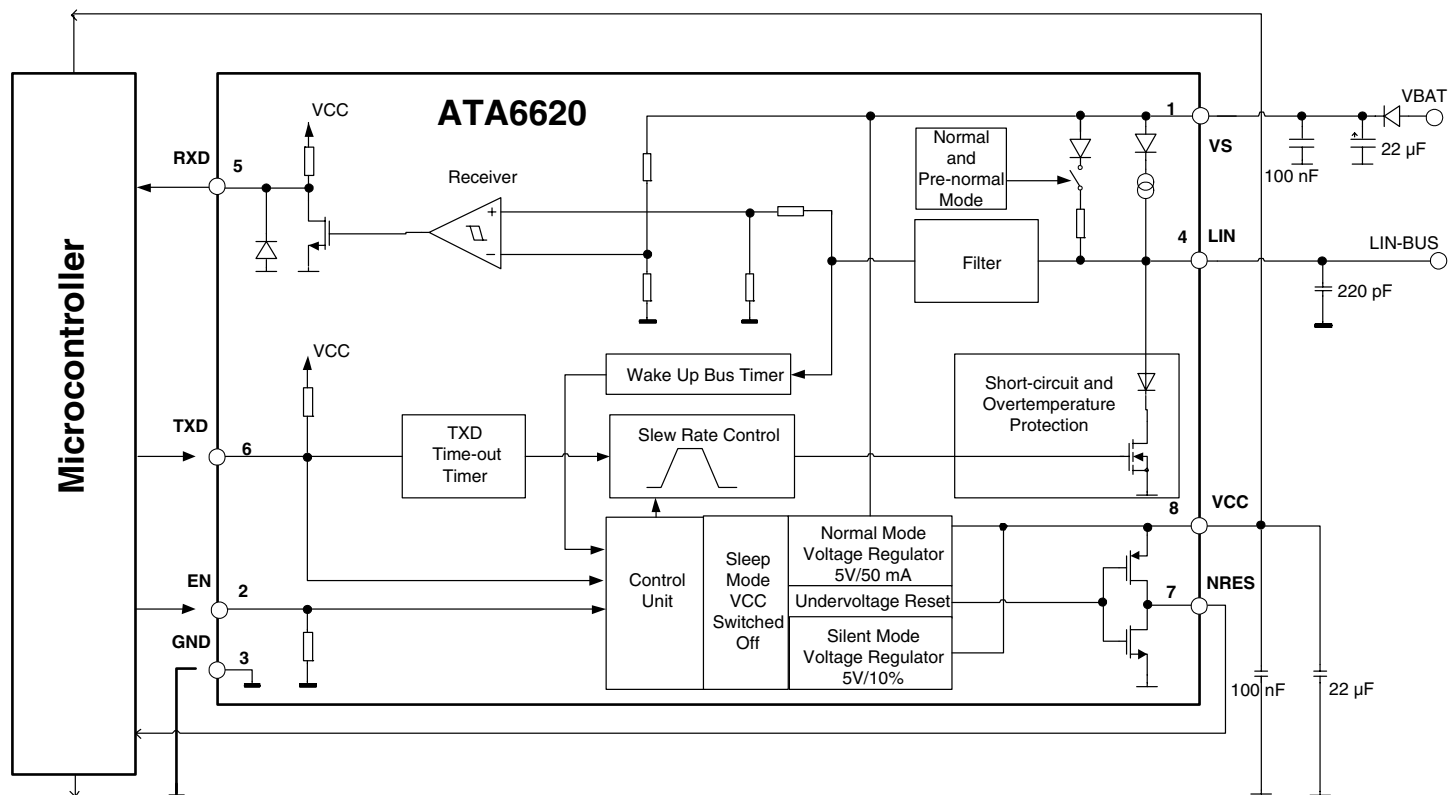


Figure 8-2. Application Circuit



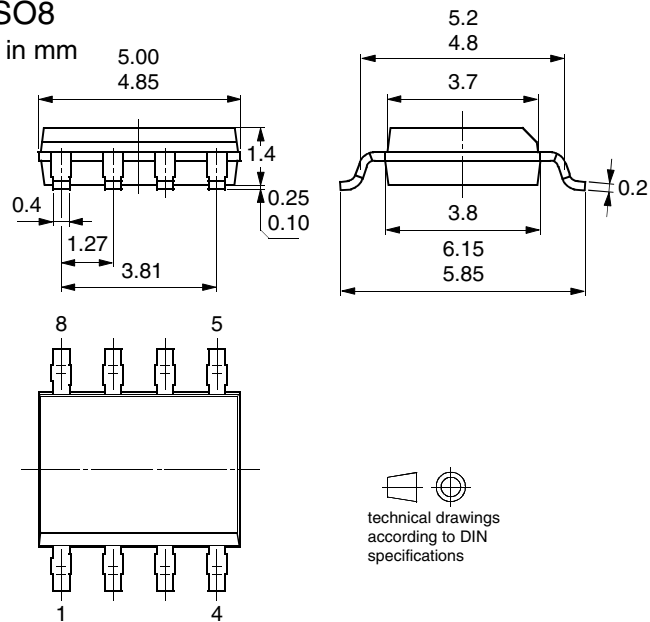
9. Ordering Information

| Extended Type Number | Package | Remarks |
|----------------------|---------|-----------------------|
| ATA6620-TAQY | SO8 | LIN System Basis Chip |

10. Package Information

Package SO8

Dimensions in mm





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